

CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHC9151FT,74VHC9152FT

#### 1. Functional Description

74VHC9151FT: 9-BIT SCHMITT BUFFER 74VHC9152FT: 9-BIT SCHMITT INVERTER

#### 2. General

The 74VHC9151FT/74VHC9152FT are an ultra-high-speed 9-bit Schmitt Buffer / Inverter fabricated using silicon-gate CMOS technology. The 74VHC9151FT/74VHC9152FT combines low power consumption of CMOS with Schottky TTL speeds.

74VHC9151FT output is a non-inverting type and the 74VHC9152FT output is an inverting type.

All the inputs have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHC9151FT/74VHC9152FT are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Additionally, all the inputs have a newly developed protection circuit without a diode returned to  $V_{CC}$ . This enables the inputs to be tolerant of up to 5 volts even when power supply is down.

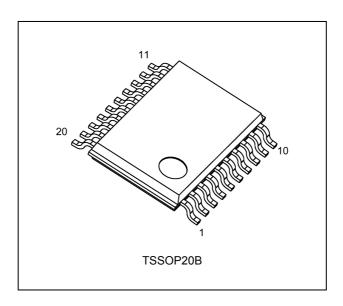
The input power-down protection capability makes the 74VHC9151FT/74VHC9152FT ideal for a wide range of applications, such as interfacing between different voltages, voltage translation from 5 V to 3 V and battery backup circuits.

#### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed:  $t_{pd} = 3.6 \text{ ns (typ.)}$  at  $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation:  $I_{CC} = 4.0 \mu A \text{ (max)}$  at  $T_a = 25 \text{ °C}$
- (5) Power down protection is provided on all inputs.
- (6) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (7) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V}$  to 5.5 V

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

### 4. Packaging



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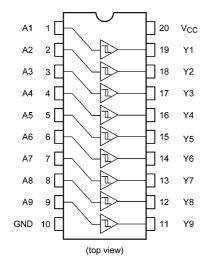
Start of commercial production

2014-06

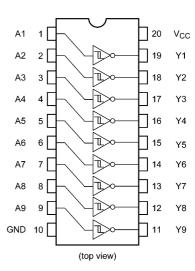


#### 5. Pin Assignment

#### 74VHC9151FT

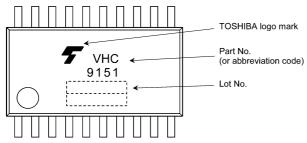


### 74VHC9152FT

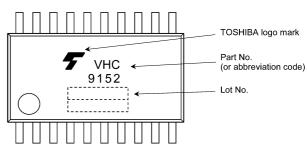


## 6. Marking

#### 74VHC9151FT



#### 74VHC9152FT



### 7. Truth Table

А	Y 74VHC9151FT	Y 74VHC9152FT
L	L	Н
Н	Н	L



#### 8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>		±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	P <sub>D</sub>	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>	·	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 9. Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 125	°C

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

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#### 10. Electrical Characteristics

## 10.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_		3.0	_		2.20	V
				4.5	_		3.15	
				5.5	_		3.85	
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90		_	V
				4.5	1.35		_	
				5.5	1.65		_	
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30		1.20	V
				4.5	0.40		1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58		_	
			I <sub>OH</sub> = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	
			I <sub>OL</sub> = 8 mA	4.5	_		0.36	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	V <sub>IN</sub> = 5.5 V or GND		_		±0.1	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	μΑ

## 10.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_		3.0	_	2.20	V
				4.5	_	3.15	]
				5.5	_	3.85	
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.48	_	
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μА

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## 10.3. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Conditio	n	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_		3.0	_	2.20	V
				4.5	_	3.15	
				5.5	_	3.85	1
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	1
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	1
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	1
			I <sub>OH</sub> = -4 mA	3.0	2.40	_	
			I <sub>OH</sub> = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	0.55	1
			I <sub>OL</sub> = 8 mA	4.5		0.55	1
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	•	0 to 5.5	_	±2.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μА

## 10.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHC9151FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	_	4.8	9.4	ns
						50	_	8.1	16.1	
					5.0 ± 0.5	15	_	3.3	6.0	
						50	_	5.7	10.5	
Propagation delay time	74VHC9152FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3\pm0.3$	15	_	4.8	9.3	ns
						50	_	7.8	15.4	
					5.0 ± 0.5	15	_	3.6	6.3	
						50	_	5.7	10.2	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	_	_	1.5	ns
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C <sub>IN</sub>		_			_	4	10	pF
Power dissipation	74VHC9151FT	C <sub>PD</sub>	(Note 2)	f <sub>IN</sub> = 1 MHz			_	11	_	pF
capacitance	74VHC9152FT							10	_	

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

Note 2:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/9 \text{ (per bit)}$ 

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## 10.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC9151FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	10.7	ns
						50	1.0	18.4	
					$5.0 \pm 0.5$	15	1.0	6.8	
						50	1.0	11.9	
Propagation delay time	74VHC9152FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	10.6	ns
						50	1.0	17.6	
					$5.0 \pm 0.5$	15	1.0	7.1	
						50	1.0	11.6	
Output skew		$t_{osLH}, t_{osHL}$	(Note 1)	_	$3.3\pm0.3$	50		1.5	ns
					$5.0 \pm 0.5$	50		1.0	
Input capacitance		C <sub>IN</sub>		_			_	10	pF

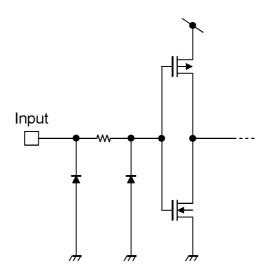
Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

# 10.6. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC9151FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	12.0	ns
						50	1.0	20.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	13.0	
Propagation delay time	74VHC9152FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	11.5	ns
						50	1.0	19.5	
					5.0 ± 0.5	15	1.0	8.0	
						50	1.0	13.0	
Output skew		$t_{osLH}, t_{osHL}$	(Note 1)	_	$3.3 \pm 0.3$	50		1.5	ns
					5.0 ± 0.5	50	_	1.0	
Input capacitance		C <sub>IN</sub>		_		·	_	10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

#### 11. Internal Equivalent Circuit



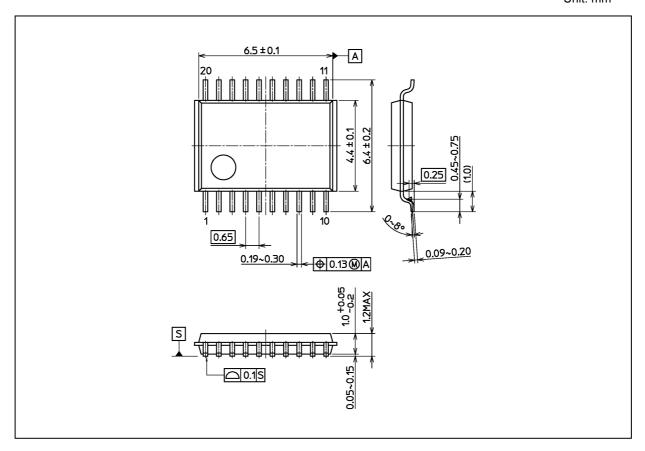
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## **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

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